

Tunable Inductive Coupler for High-Fidelity Gates Between Fluxonium Qubits

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The fluxonium qubit is a promising candidate for quantum computation due to its long coherence times and large anharmonicity. We present a tunable coupler that realizes strong inductive coupling between two heavy-fluxonium qubits, each with approximately 50-MHz frequencies and approximately 5-GHz anharmonicities. The coupler enables the qubits to have a large tuning range of XX coupling strengths (-35 to 75 MHz). The ZZ coupling strength is <3 kHz across the entire coupler bias range and <100 Hz at the coupler off position. These qualities lead to fast high-fidelity single- and two-qubit gates. By driving at the difference frequency of the two qubits, we realize a $\sqrt{i\text{SWAP}}$ gate in 258 ns with fidelity 99.72%, and by driving at the sum frequency of the two qubits, we achieve a $\sqrt{b\text{SWAP}}$ gate in 102 ns with fidelity 99.91%. This latter gate is only five qubit Larmor periods in length. We run cross-entropy benchmarking for over 20 consecutive hours and measure stable gate fidelities, with $\sqrt{b\text{SWAP}}$ drift (2σ) $<0.02\%$ and $\sqrt{i\text{SWAP}}$ drift $<0.08\%$.

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I. INTRODUCTION

Superconducting circuits are a promising platform for the development of scalable error-corrected quantum computation, heralded by many recent advances toward

large-scale quantum processors [1,2] and improvements on the performance of qubits and gate operations [3–5]. These advances have relied on the transmon qubit [6] and, through collective effort, these qubits have achieved excellent coherence times [5,7] and gate fidelities approaching the quantum error-correction threshold [8–10].

A promising alternative to the transmon is the fluxonium qubit [11], which has attractive properties including a nearly degenerate ground state and a large anharmonicity. Compared to other qubits fabricated with similar material qualities, low-frequency qubits have less dielectric loss and thus a slower decoherence rate. The large anharmonicity mitigates the speed limit for qubit operations in transmons and enables quantum gates that are as fast or even faster despite low qubit frequencies [12]. In addition, one can flux tune the fluxonium qubit to be noise biased, increasing energy coherence ($T_1 > 5$ ms) at the expense of being more phase sensitive [13,14]. Recent works have demonstrated approximately 1 ms coherence times and

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>99.9% fidelity single-qubit gates using fluxonium qubits [15–17]. In addition, one can flux tune the fluxonium qubit to be noise biased, increasing energy coherence ($T_1 > 5$ ms) at the expense of being more phase sensitive [13,14].

Beyond single-qubit operations, several recent works have demonstrated high-fidelity two-qubit fluxonium gates using either fixed capacitive coupling [18–21] or a tunable capacitive coupler [17,22]. While these two-qubit gate schemes are promising, they either populate states outside of the computational subspace or use high-frequency fluxonium qubits. In this work, we realize a tunable *inductive* coupler and perform (>99.9%) fidelity two-qubit gates. Our inductive coupler, similar to the g-mon coupler [23,24], realizes a large interaction strength even for low-frequency qubits, without involving higher energy levels. This enables the gate to take advantage of the full coherence of the fluxonium while avoiding any leakage to states outside the logical subspace.

In Sec. II, we provide theoretical analysis of our tunable inductive coupler, showing the origins of XX coupling. We also find that both the XX and unwanted ZZ coupling can be turned off, allowing for an operational spot for single-qubit gates. In Sec. III, we report the

characterization of our device near this operational spot, measuring the ZZ coupling to be <100 Hz. Finally, in Sec. IV, we construct $\sqrt{i\text{SWAP}}$ and $\sqrt{b\text{SWAP}}$ gates using this XX interaction. We demonstrate the tuning of these gates and estimate their fidelities using various benchmarking protocols.

II. INDUCTIVELY COUPLED HEAVY-FLUXONIUM QUBITS

In this paper, we use a tunable inductive coupler, inspired by designs from Refs. [23–26], to realize strong coupling between two fluxonium qubits. Each qubit is individually described by the Hamiltonian

$$H_f = -4E_C \frac{d^2}{d\varphi^2} - E_J \cos(\varphi) + \frac{1}{2}E_L \left(\varphi + 2\pi \frac{\Phi_{\text{ext}}}{\Phi_0} \right)^2, \quad (1)$$

where $E_C = e^2/(2C_q)$ denotes the charging energy, C_q is the total shunting capacitance of the qubit, E_J is the Josephson energy of the small junction, $E_L = \Phi_0^2/(4\pi^2 L_{JA})$ is the inductive energy, and L_{JA} is the total

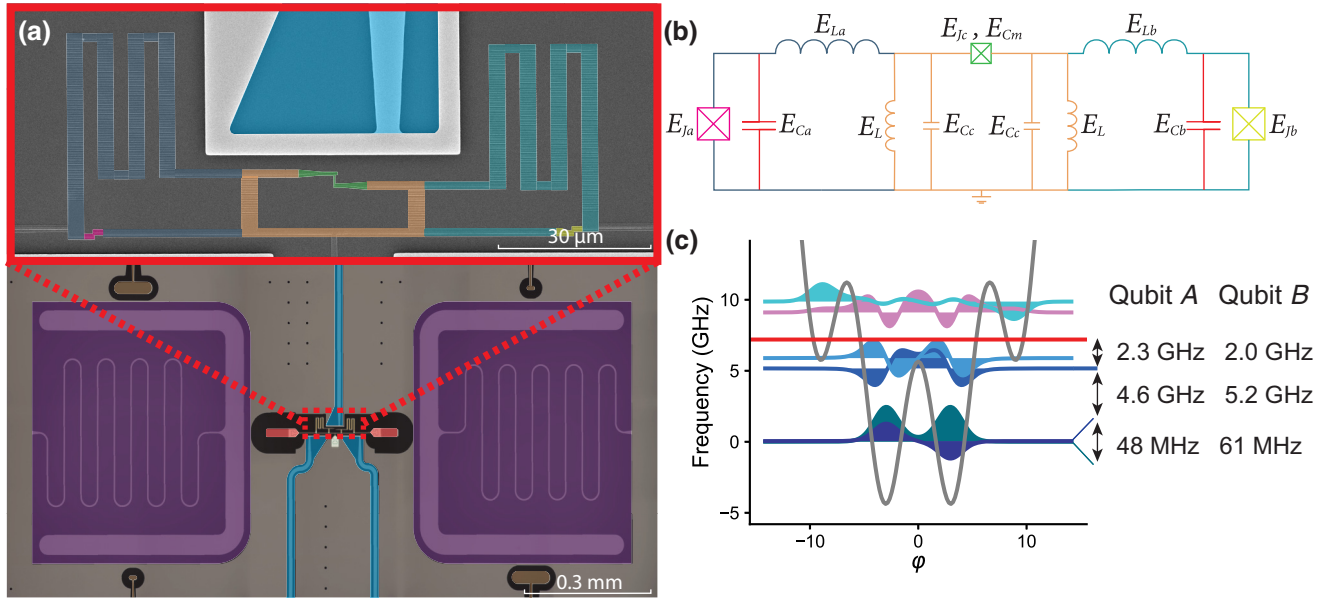


FIG. 1. The device, circuit, and energy-level diagram. (a) Top panel: False-colored scanning electron microscope image of the two fluxoniums and coupler junction loops. Each qubit consists of a small Josephson junction (pink and yellow) and an array of large junctions as an inductor (blue and cyan). The coupler consists of a small Josephson junction (green) and a shorter array of junctions (orange). Bottom panel: optical microscope image of the flux control lines (light blue), readout resonators (purple), qubit shunting capacitors (red), and resonator drive and readout lines (brown). (b) Circuit diagram for the coupled fluxoniums with the tunable coupler. The colors of the components correspond to the colors in the device images. (c) Energy-level diagram of the heavy-fluxonium wave functions at the flux-frustration point ($\Phi_{\text{ext}} = \Phi_0/2$), plotted using qubit-B parameters. The gray line represents the potential well, and the red line is at the readout resonator frequency. The first six energy eigenstate wave functions are plotted with solid colors. The qubit frequencies, anharmonicities, and resonator detunings for qubits A and B are indicated with black arrows.

inductance of the superinductor. $\Phi_0 = h/2e$ is the superconducting flux quantum and Φ_{ext} denotes the flux threading the loop. We design heavy-fluxonium qubits [Fig. 1(a)] with large E_J/E_C , such that at half-integer flux bias, our qubits, labeled as A and B , have small splittings ($\omega_A/2\pi = 48$ MHz and $\omega_B/2\pi = 61$ MHz) and large anharmonicities ($\alpha_A = 4.6$ GHz and $\alpha_B = 5.2$ GHz). See Fig. 1(c) for the qubit-level structure at the sweet spot ($\Phi_{\text{ext}} = \Phi_0/2$) and Table I for the qubit parameters.

These two heavy-fluxonium qubits are linked via an inductive coupler, as shown in Fig. 1(b). This full circuit, analyzed in Appendix A, consists of four degrees of freedom: the two fluxonium qubits and the two coupler degrees of freedom—one harmonic and one fluxoniumlike. Ignoring the negligible cross capacitance, these two fluxonium qubits do not directly interact with each other; instead, they each share an inductance (E_L) with the tunable coupler. Although the galvanic coupling is relatively strong, the coupler excitation energies (9.5 GHz) are well above the energies associated with qubit excitations, leading to a dispersive interaction. Thus, near half-integer flux for the qubits, we can use a perturbative treatment, creating an effective Hamiltonian up to fourth order [27]:

$$H_{\text{eff}} = \sum_{\mu=A,B} \left(-\frac{\omega_\mu}{2} \sigma_z^\mu - \Omega_\mu \sigma_x^\mu \right) + J \sigma_x^A \sigma_x^B + \zeta \sigma_z^A \sigma_z^B, \quad (2)$$

where σ_x^μ and σ_z^μ are the qubit Pauli operators in the basis of symmetric and antisymmetric wave functions.

The first term in the effective Hamiltonian describes the qubit frequencies, including the Lamb shifts induced by the coupler. The second term captures the effect of qubit flux bias, which we use for single-qubit gates [12]. This term additionally incorporates a first-order perturbative

TABLE I. The parameters and basic properties for the qubits. Measurements are made when the fluxonium qubits are biased at their half-flux sweet spots, while the coupler φ_- mode is biased at $\Phi_{\text{ext},C}/\Phi_0 = 0.3$. The energy splittings are the differences between the bare-ground- and first-excited-state energies $f_{10} = f_1 - f_0$, while the anharmonicity is defined as $\alpha = f_{21} - f_{10}$. Circuit parameters in gigahertz are used throughout this work. T_2 in this table refers to the values when the other qubit is at its ground state.

	Qubit A	Qubit B	Coupler φ_-	Coupler φ_+
f_{10} (GHz)	0.0484	0.0618	9.52	15.6
α (GHz)	5.06	4.41	0.93	0
T_1 (μ s)	300	180		
T_2^* (μ s)	200	150		
T_{2e} (μ s)	300	250		
E_J (GHz)	4.88	5.65	4.246	
E_C (GHz)	0.905	0.95	8	12
E_L (GHz)	0.286	0.292	3.52	3.52

shift due to the fluxoniumlike coupler degree of freedom. The third term is the desired XX coupling, where J is a function of the coupler flux $\Phi_{\text{ext},C}$. Virtual exchanges through coupler excitations leads to a $\varphi_A \varphi_B$ term, which can be truncated to $\sigma_x^A \sigma_x^B$. There are two contributions here: a static one, due to the harmonic coupler degree of freedom, and a flux-tunable one, from the fluxoniumlike coupler degree of freedom (see Ref. [27]). Because these contributions have opposite signs, we can null J at a particular $\Phi_{\text{ext},C}$, which we term the “off position.” The final term describes a small unwanted ZZ interaction that comes from fourth-order perturbation theory.

This effective Hamiltonian governs our operation of the two-qubit device: a parametric drive controls J , allowing us to achieve two-qubit gates, and a particular $\Phi_{\text{ext},C}$ bias fully turns off the qubit-qubit coupling. However, since Ω_μ is coupler-flux dependent, this tuning causes shifts of the fluxonium qubits away from their sweet spots. The qubit fluxes must then be tuned to compensate for these shifts. Thus, while constraining the qubits to remain at their sweet-spot locations, we perform an effectively one-dimensional sweep over the coupler flux to locate the off position [27]. We refer to this sweep as the “sweet-spot contour.” Along the sweet-spot contour, ζ is generally nonzero but numerically we find that $\zeta < 3$ kHz. Effectively, this ZZ term can be cancelled via small ($< 10^{-5} \Phi_0$) flux shifts away from the qubit sweet spot. We find the flux noise at this bias point not to be the dominant dephasing mechanism, as it would only limit the pure-qubit dephasing time to 1 ms (see Appendix C).

III. DEVICE CHARACTERIZATION

We measure the properties of a fabricated two-dimensional (2D) superconducting device, validating our theoretical analysis of the tunable inductive coupler and calibrating it for single- and two-qubit gates. We use a tantalum base layer for increased qubit coherence [7,28] and we use double-angle aluminum evaporation [29] to fabricate the Josephson junctions (see Appendix F). The geometry of the device is shown in Fig. 1(a). There are 205 Josephson junctions in the superinductor of each qubit (E_{LA} and E_{LB}) and 17 junctions in each superinductor of the tunable coupler (E_L). There are three dedicated control lines, one for each of the qubits and one for the coupler, which are used for both dc biasing as well as rf-flux driving (see Appendix E).

There are two lumped LC resonators capacitively coupled to the fluxoniums for readout. These readout resonators have line widths of approximately 1.1 MHz and dispersive shifts of approximately 0.7 MHz from the computational levels. Since the qubit frequencies correspond to a temperature (approximately 3 mK) that is lower than the environment temperature, we must always initialize the qubit. We use a measurement-based active reset protocol

for initialization [30,31], enabled by the QICK controlled radio-frequency system on chip (RFSoc) [32]. The reset is carried out by measuring the qubit state and conditionally playing a single-qubit π pulse, completed within 800 ns. With this method, we initialize the qubits with approximately 95% fidelity, primarily limited by our measurement infidelity (which could be improved by using quantum noise-limited amplifiers; see Appendix G).

To determine the coupler parameters, we scan the coupler flux over the range of $\Phi_{\text{ext},C}/\Phi_0 = 0.24$ to $\Phi_{\text{ext},C}/\Phi_0 = 0.34$ and measure qubit frequencies while staying on the “sweet-spot contour,” shown in Fig. 2(a). Since $\Omega_{A,B}$ is zero along this contour, we determine the XX

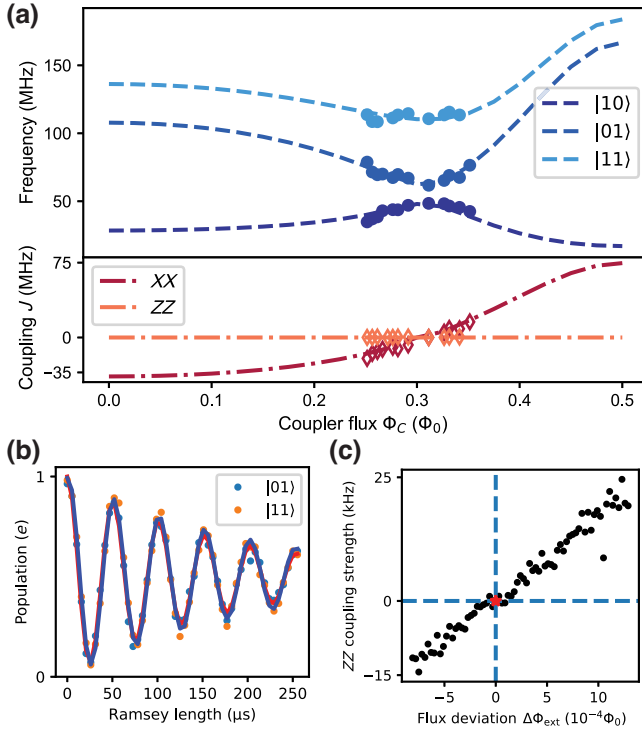


FIG. 2. Measurements of the XX and ZZ coupling strength. (a) Top panel: the measured $|01\rangle$, $|10\rangle$, and $|11\rangle$ frequencies as a function of the coupler flux as the qubits are tuned to be along the “sweet-spot contour.” The dashed lines are from full numerical simulations with parameters extracted from qubit spectroscopy (see Appendix A). Bottom panel: the XX and ZZ coupling strength (diamonds) extracted from the data (dots). Numerical-simulation predictions are plotted as the dashed lines. The ZZ coupling strength is <3 kHz across the entire coupler flux range. (b) A Ramsey experiment with qubit B at the coupler “off position,” with the qubits initialized in either $|01\rangle$ or $|11\rangle$. The frequency difference $(f_{11} - f_{10}) - (f_{01} - f_{00})$, extracted using Ramsey fits with different qubit initial states, measures the ZZ coupling strength to be <100 Hz. (c) We perform this same measurement on qubit A while sweeping its flux away from the “sweet-spot contour.” We find that the ZZ coupling strength becomes nonzero, which we use as an indicator for fine-tuning qubit flux biases.

coupling strength J from observing the qubit frequency shifts in the dressed Hamiltonian. We measure the ZZ coupling strength by taking the difference of the frequency of qubit B when qubit A is at $|0\rangle$ and $|1\rangle$. We fit the full model of the circuit to the data and find that J can be tuned to zero at $\Phi_{\text{ext},C}/\Phi_0 \sim 0.3$, where $f_{01} - f_{10}$ is at its minimum. Within the range of coupler flux that we measure, J is tuned from -20 MHz to 15 MHz. Over the whole range of coupler flux, $\Phi_{\text{ext},C}/\Phi_0 = 0$ to $\Phi_{\text{ext},C}/\Phi_0 = 0.5$, numerical simulations show that J can range between -35 MHz and 70 MHz [see Fig. 2(a)]. These coupling strengths are large, of the order of individual qubit frequencies ($J \sim \omega_\mu$).

To measure the precise ZZ coupling strength, we perform Ramsey experiments on qubit B , with qubit A in its ground or excited states [see Fig. 2(b)]. We then vary the flux near the qubit sweet spots, measuring the ZZ coupling strength. As predicted by our theory, we find a <100 Hz ZZ coupling-strength point at the maximum T_2 point [see Fig 2(c)], implying an on-off contrast $>10^5$. At this coupler off position, qubit A (qubit B) T_1 is 180 μs (300 μs) and T_{2e} is 250 μs (300 μs) (see Table I).

We bias the tunable coupler at the off position and realize both single- and two-qubit controls with rf-flux drives. Due to significant (approximately 20%) geometric dc- and rf-flux crosstalk in our system, we have off-resonant drives on both qubits. (In larger-scale chips, this level of crosstalk can be reduced by implementing a number of recent innovations [33–35].) This effectively causes dynamic qubit frequency shifts as well as unwanted ZX , XZ , and ZZ drive terms (see Appendix D). Therefore, we develop a method to calibrate the rf-flux crosstalk by measuring its effect on qubit frequencies (see Appendix H) and apply crosstalk-cancellation pulses in our two-qubit gates.

To dynamically activate the XX coupling, we rf drive the coupler near the difference ($f_{01} - f_{10}$) and sum ($f_{01} + f_{10}$) frequencies of the two qubits (see Fig. 3). We sweep the frequency and length of this pulse at drive amplitudes of $0.5\%\Phi_0$ ($1.1\%\Phi_0$) and observe chevrons of correlated oscillations between $|01\rangle$ and $|10\rangle$ ($|00\rangle$ and $|11\rangle$), finding an oscillation rate of 0.83 MHz (2.50 MHz). The offset from the expected frequencies is small, indicating that the crosstalk cancellation is effective.

IV. SINGLE- AND TWO-QUBIT GATES

We develop fast high-fidelity single- and two-qubit gates with our device. For the single-qubit gates, we flux modulate the qubits at their corresponding bare-qubit frequencies. With qubit frequencies at 48.4 and 61.8 MHz, we calibrate single-qubit $\pi/2$ gates using Gaussian pulses with length 83.3 and 65.1 ns, which is approximately four qubit Larmor periods. We update the phases of subsequent drive pulses to implement virtual Z gates [36]. We

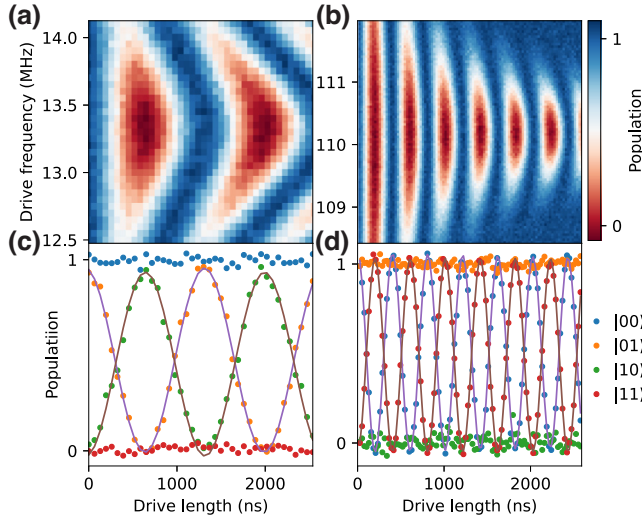


FIG. 3. The sweeping coupler drive frequencies near the difference ($f_{01} - f_{10}$) and sum ($f_{01} + f_{10}$) of the qubit frequencies generates chevron patterns. (a) The $|01\rangle \leftrightarrow |10\rangle$ chevron centered at 13.3 MHz. (b) The $|00\rangle \leftrightarrow |11\rangle$ chevron centered at 110.2 MHz. (c) After initializing the qubit to each of the four basis states, we drive the coupler at the optimal frequency and measure the population of qubit A . When driving at the difference frequency (13.3 MHz), a correlated oscillation occurs between $|01\rangle$ and $|10\rangle$, where one oscillation period takes 1200 ns. The solid line indicates the best fit to the data. (d) When driving at the sum frequency (110.2 MHz), correlated oscillations occur between $|00\rangle$ and $|11\rangle$, where one oscillation period takes 400 ns.

use simultaneous randomized benchmarking [37] to measure average single-qubit Clifford-gate fidelities, initially measuring qubit- A (qubit- B) fidelities of 99.90%(99.88%), limited primarily by coherent errors. Thus, we further optimize the single-qubit gates using derivative removal by adiabatic gate (DRAG) shaping [38], finding that the single-qubit gate fidelities increase to 99.94% and 99.95%, respectively, for each qubit [see Fig. 4(a)].

After pulse shaping, the remaining gate infidelity is primarily from qubit decoherence. Using a master equation to simulate gate infidelities, we estimate contributions of qubit decay and dephasing to be 4×10^{-4} and 3×10^{-4} , respectively. With our current pulse length, the pulse-energy deviation from different carrier-envelope phases is not the limiting factor of our single-qubit gate fidelities. The error from such deviations is less than 1×10^{-5} , far lower than the dominant decoherence contribution. We also evaluate the contribution of the Bloch-Siegert shift at this drive strength to be 5.6×10^{-5} . The complete error analysis, including other sources of error, is performed in Appendix J.

For two-qubit gates, due to the negligibly small ZZ interaction strength and the tunable XX coupling, the intuitive

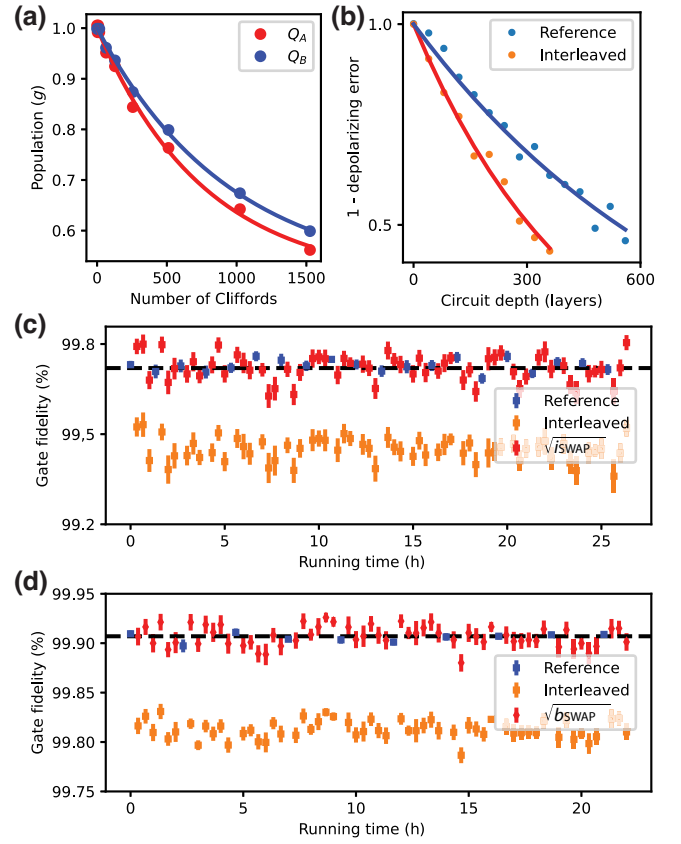


FIG. 4. The measured single- and two-qubit gate fidelities. (a) Simultaneous single-qubit randomized benchmarking. The average single-qubit Clifford-gate fidelity of qubit A (qubit B) is 99.94% (99.95%). (b) Cross-entropy benchmarking data, where “Reference” consists of layers of single-qubit gates and “Interleaved” includes an interleaved $\sqrt{b}$ SWAP gate. The depolarizing error is extracted following the procedure in Ref. [39]. The “Reference” gate fidelity is 99.90% and the “Interleaved” gate fidelity is 99.83%. This results in a $\sqrt{b}$ SWAP gate fidelity of 99.93%. (c) >25 -h-long consecutive cross-entropy benchmarking runs for $\sqrt{i}$ SWAP gates, showing an average gate fidelity (dashed line) of 99.72%. The error bars per point indicate the statistical-fit uncertainty. (d) >20 -h-long consecutive cross-entropy benchmarking runs for $\sqrt{b}$ SWAP gates, showing an average gate fidelity (dashed line) of 99.91%.

choices for our native two-qubit gates are

$$\begin{aligned} \sqrt{i}\text{SWAP} &= \begin{pmatrix} 1 & 0 & 0 & 0 \\ 0 & 1/\sqrt{2} & i/\sqrt{2} & 0 \\ 0 & i/\sqrt{2} & 1/\sqrt{2} & 0 \\ 0 & 0 & 0 & 1 \end{pmatrix}, \\ \sqrt{b}\text{SWAP} &= \begin{pmatrix} 1/\sqrt{2} & 0 & 0 & i/\sqrt{2} \\ 0 & 1 & 0 & 0 \\ 0 & 0 & 1 & 0 \\ i/\sqrt{2} & 0 & 0 & 1/\sqrt{2} \end{pmatrix}. \end{aligned} \quad (3)$$

These gates are fully entangling and have been used in demonstrating quantum advantage [1]. Furthermore, by embedding a π pulse between $\sqrt{i\text{SWAP}}$ or $\sqrt{b\text{SWAP}}$ gates, we can compile controlled-NOT (CNOT) and controlled-Z (CZ) gates while also echoing out low-frequency noise.

Using data shown in Fig. 3, we calibrate a $\sqrt{i\text{SWAP}}$ ($\sqrt{b\text{SWAP}}$) gate that takes 257.8 ns (101.6 ns). Because the drive frequency of $\sqrt{i\text{SWAP}}$ ($\sqrt{b\text{SWAP}}$) is 13.4 MHz (110.2 MHz), there are only four (11) oscillation periods in a single gate pulse. In the case of the $\sqrt{i\text{SWAP}}$ pulse, the use of a shorter gate length causes the carrier-envelope phase to affect the energy of the pulse (see Appendix J2).

These two-qubit gates have three phase degrees of freedom, which can be calibrated by applying two virtual single-qubit Z_ϕ gates as well as adjusting the coupler drive phase. We amplify the error associated with miscalibrated phases using specially designed sequences, allowing us to execute a pure $\sqrt{i\text{SWAP}}$ or $\sqrt{b\text{SWAP}}$ gate. This calibration method is detailed in Appendix I.

We measure the two-qubit gates using process tomography but this method is limited in fidelity precision by our state-preparation and -measurement (SPAM) errors [40] to be 95% (see Appendix I). Therefore, we perform a more precise gate-fidelity measurement by amplifying gate errors and using other methods, such as cross-entropy benchmarking [1,41] and interleaved randomized benchmarking [42].

We implement cross-entropy benchmarking by interleaving $\sqrt{i\text{SWAP}}$ ($\sqrt{b\text{SWAP}}$) gates between random single-qubit gates. To subtract the errors of the single-qubit gates, we first measure a reference sequence that has the same number of layers, where each layer consists of a $\pi/2$ gate and a Z gate on each qubit, both with randomly selected phases ($\phi = n\pi/4, n \in [0, 7]$). The depolarizing error [39,41] is found by varying the number of layers and measuring the qubit state population. Then, we repeat the process with the interleaved sequence. Because the reference gates are randomly sampled, we can calculate the depolarizing error of the two-qubit gate as $p = p_{\text{interleaved}}/p_{\text{reference}}$. We subsequently find the gate fidelity from the gate depolarizing error with

$$F = p + (1 - p)/D, \quad (4)$$

where p is the depolarizing error of the two-qubit gate, D is the dimension of the Hilbert space, and F is the gate fidelity.

We continuously perform cross-entropy benchmarking for both $\sqrt{i\text{SWAP}}$ and $\sqrt{b\text{SWAP}}$ gates for more than 20 h, as shown in Fig. 4. For $\sqrt{i\text{SWAP}}$, we interleave it in reference sequences consisting of single-qubit gates made of Gaussian pulses. We measure an average reference sequence depolarizing error of approximately 3.2×10^{-3} and an average interleaved sequence depolarizing error of approximately 6×10^{-3} . Using Eq. 4, we derive an average

$\sqrt{i\text{SWAP}}$ fidelity $99.72 \pm 0.04\%$. For $\sqrt{b\text{SWAP}}$, we implement DRAG pulses on the single-qubit gates to improve the reference sequence fidelity. We measure a depolarizing error of approximately 1.3×10^{-3} of the reference sequences and a total depolarizing error of approximately 2.4×10^{-3} of the interleaved sequences, which results in a $\sqrt{b\text{SWAP}}$ gate fidelity $99.91 \pm 0.01\%$.

We compute the error budget of our single- and two-qubit gates, taking into account decoherence and other error channels, in Table II. For all gates, qubit decoherence is the dominant source of error, while the beyond rotating-wave approximation (RWA) errors and carrier-envelope errors caused by using slow qubits are much lower, which shows the feasibility of high-fidelity gates within the low-frequency regime.

Finally, we construct a CNOT gate with two $\sqrt{b\text{SWAP}}$ gates and five single-qubit gates and measure a CNOT fidelity of 99.5% with two-qubit interleaved randomized benchmarking. This result is consistent with our previously measured single-qubit and $\sqrt{b\text{SWAP}}$ gate fidelities and can be further improved with better circuit compilation.

V. CONCLUSIONS

We have presented a tunable coupler design for heavy-fluxonium qubits, which utilizes inductive coupling to take advantage of the large phase matrix elements. This coupler can achieve strengths that rival the single-qubit energies and can also be turned off, nulling the coupling strength to much less than the coherence time. The qubits retain high coherences and high fidelity of single-qubit gates ($>99.94\%$) from simultaneous randomized benchmarking. We have demonstrated fast high-fidelity $\sqrt{i\text{SWAP}}$ and $\sqrt{b\text{SWAP}}$ gates by parametrically driving the coupler and we have achieved over 99.9% two-qubit gate fidelity for the $\sqrt{b\text{SWAP}}$ gate.

In this architecture, all gate operations take place fully within the computational subspace, without occupation of higher levels. All gate operations use moderate-frequency rf pulses ranging from approximately 10 MHz to 100 MHz, which can easily be synthesized by direct digital synthesis. These demonstrated advantages can help explore a new regime of circuit design and gate schemes in the future.

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APPENDIX A: FULL CIRCUIT MODEL

The full Hamiltonian of the circuit shown in Fig. 1(b) is $H = H_{\text{qubit}} + H_{\text{coupler}} + V$, where

$$H_{\text{qubit}} = \sum_{\mu=A,B} [4E_{C\mu} n_{\mu}^2 + \frac{1}{2} E_{L\mu} \varphi_{\mu}^2 + E_{J\mu} \cos(\varphi_{\mu} + \pi)], \quad (\text{A1a})$$

$$H_{\text{coupler}} = 4E_{C-} n_{-}^2 + \frac{1}{2} E_{LC} \varphi_{-}^2 - E_{Jc} \cos(\varphi_{-} + 2\pi \Phi_c / \Phi_0) + 4E_{C+} n_{+}^2 + \frac{1}{2} E_{LC} \varphi_{+}^2, \quad (\text{A1b})$$

$$V = -\frac{E_{LA}}{2} [\varphi_a(\varphi_{+} + \varphi_{-})] - \frac{E_{LB}}{2} [\varphi_b(\varphi_{+} - \varphi_{-})] + \sum_{\mu=A,B} \frac{E_{L\mu}}{2} \delta\phi_{\mu} [-2\varphi_{\mu} + \varphi_{+} + (-1)^{\mu} \varphi_{-}], \quad (\text{A1c})$$

in which $[\varphi_{\mu}, n_{\nu}] = i\delta_{\mu\nu}$, $\mu = A, B, -, +$, and we have defined $E_{LC} = \frac{1}{2}(\frac{1}{2}[E_{LA} + E_{LB}] + E_L)$, $E_{C+} = 2E_{Cc}$, and $E_{C-} = (1/E_{Cm} + 1/[2E_{Cc}])^{-1}$. All other circuit parameters can be read off from Fig. 1(b). To account for the need to tune the qubit flux as a function of the coupler flux, as discussed in the main text, we define $\delta\phi_{\mu} = \phi_{\mu} - \pi$. For further details on the derivation of Eq. (A1), see Ref. [27].

We comment briefly on how the effective Hamiltonian Eq. (2) arises from Eq. (A1). The XX operator content of the effective coupling between the qubits can be traced back to the operator form of the coupling between the qubits and the couplers, $\varphi_{\mu}\varphi_{\pm}$. The phase operator in the qubit subspace of a fluxonium qubit biased at the sweet spot can be written as $\langle 1|\varphi|0\rangle\sigma_x$ [12]. Thus, one application of the perturbing term $\varphi_a\varphi_{\pm}$ swaps, e.g., an excitation of qubit A into the coupler and an application of $\varphi_b\varphi_{\pm}$ returns this excitation to the qubit subspace in the form of an excitation of qubit B (for further details, see Ref. [27]).

Using this Hamiltonian, we locate the sweet-spot contour by minimizing the eigenenergy E_{1100} as a function of the qubit fluxes, keeping the coupler flux fixed. The

off position is then found by performing the same minimization along the sweet-spot contour as a function of the coupler flux.

APPENDIX B: PLASMON SPECTROSCOPY AND FULL MODEL FITTING

To determine the physical parameters of our system, we measure the two-tone spectroscopies of higher-frequency (approximately 5 GHz) transitions. Each qubit is charge driven through the readout resonator while the resonator is being probed. We see a sharp change in the resonator transmission when a qubit transition is driven on resonance. Thus, by sweeping different flux biases, we can see a frequency-flux 2D qubit spectroscopy. We measure the transition frequencies from the ground state to first and second plasmon states ($|20\rangle$ and $|30\rangle$) for qubit A while changing the qubit- A flux bias. Because $|10\rangle$ has significant thermal population around the $\Phi_{\text{ext},A} = 0.5\Phi_0$ bias point, we can also see transitions from it to the higher levels [see Fig. 5(a)]. Similarly, we measure transition frequencies for qubit B [see Figs. 5(b) and 5(c)]. Using the SCQUBITS software package [43,44], we subsequently fit the spectroscopy data with the full Hamiltonian Eq. (A1), as shown in overlay lines in Fig. 5. Because our dc-flux crosstalk matrix is not perfectly calibrated across this range, we cannot keep the coupler and the other qubit flux biases precisely at the same point during a flux sweep, leading to slight mismatches between the theory curves and experimental data.

APPENDIX C: ZZ SUPPRESSION

The suppression of static ZZ coupling is an attractive feature of our architecture, allowing for large on-off ratios. This suppression is achieved by cancelling out two contributions of ZZ by fine tuning the qubit flux bias. To see this, we start from the effective Hamiltonian

$$H_{\text{eff}} = - \sum_{\mu=A,B} \frac{\omega_{\mu}}{2} \sigma_z^{\mu} - \Omega_{\mu} \sigma_x^{\mu} + J \sigma_x^A \sigma_x^B + \zeta \sigma_z^A \sigma_z^B, \quad (\text{C1})$$

where the Pauli operators are defined in the eigenbasis of the system at the off position. The static ZZ shift ζ is small for a number of reasons. First, ζ is generally suppressed in low-frequency fluxonium architectures, due to the large detuning between the qubit excitation energies and the energies of the higher-lying states [18]. Second, the galvanic coupling architecture helps suppress ζ because the phase matrix elements of qubit states with higher-lying fluxonium states are very small relative to charge matrix elements. Finally, there is no direct coupling between the qubits in this architecture. Thus, second- and third-order contributions to ζ vanish, with the leading-order contribution arising only at fourth order in perturbation theory

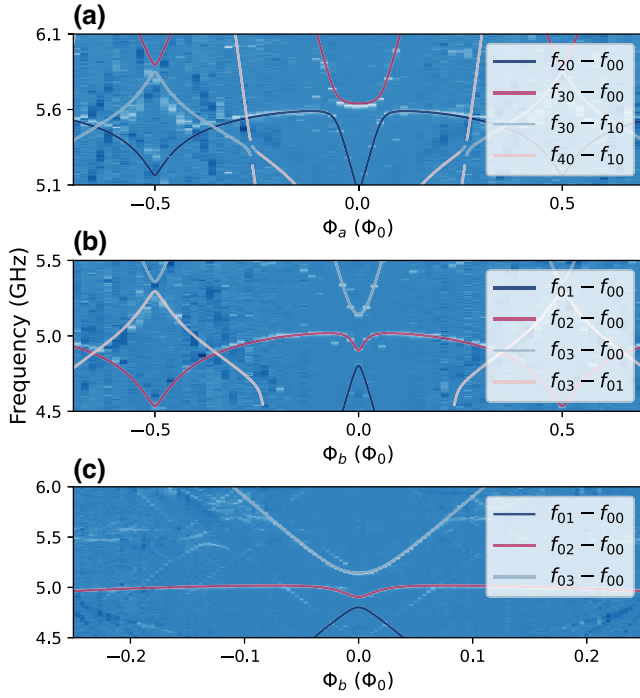


FIG. 5. The plasmon-spectroscopy features of both qubits. (a) The $|00\rangle \rightarrow |20\rangle$ and $|00\rangle \rightarrow |30\rangle$ transition frequency versus the qubit-*A* flux bias. (b) The $|00\rangle \rightarrow |02\rangle$ and $|00\rangle \rightarrow |03\rangle$ transition frequency versus the qubit-*B* flux bias. (c) An enlargement of the plot around $\Phi_{\text{ext},B} = 0$. The data were taken with the coupler flux around 0 and the flux of the other qubit fixed at 0.

[9,17,45]. Sweeping the coupler flux while keeping qubits at their sweet spots ($\Omega_\mu = 0$), $|\zeta|$ is nonvanishing and on the order of 1 kHz.

However, ζ can be canceled with a nonzero Ω_μ by qubit-flux-dependent shifts away from the sweet-spot contour. To see this, we diagonalize the single-qubit terms in Eq. (C1) up to second order of Ω_μ/ω_μ using the unitary transformation $U = \exp(-i \sum_{\mu=A,B} (\Omega_\mu/\omega_\mu) \sigma_{y\mu})$, yielding

$$\begin{aligned}
 H'_{\text{eff}} &= U^\dagger H_{\text{eff}} U \\
 &= - \sum_{\mu=A,B} \frac{\omega_\mu + 2 \frac{\Omega_\mu^2}{\omega_\mu}}{2} \sigma_z^\mu \\
 &\quad + J \left(\sigma_x^A + \frac{2\Omega_A}{\omega_A} \sigma_z^A \right) \left(\sigma_x^B + \frac{2\Omega_B}{\omega_B} \sigma_z^B \right) + \zeta \sigma_z^A \sigma_z^B,
 \end{aligned} \tag{C2}$$

where we have expanded the result to second order in the small parameters Ω_μ/ω_μ and ignored negligible corrections arising from the last term in Eq. (C2). Thus the

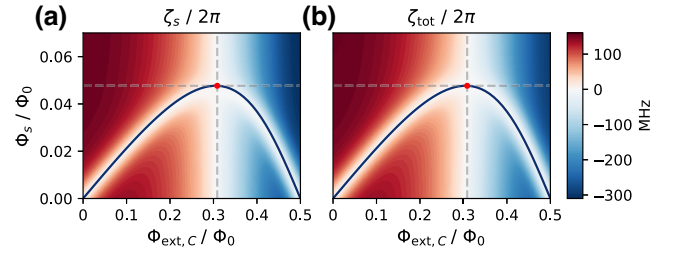


FIG. 6. The ZZ interaction strength (a) ζ_s obtained from the effective model and (b) ζ_{tot} from numerical diagonalization of the full model. Both quantities are plotted as a function of the qubit flux shifts $\Phi_s \equiv \Phi_{\text{ext},A} - 0.5\Phi_0 = 0.5\Phi_0 - \Phi_{\text{ext},B}$ and the coupler flux $\Phi_{\text{ext},C}$. In both plots, the red circle marks the off position and the solid curves are the “sweet-spot contours.” We find that ζ_s is the main contributor to ζ_{tot} and that ζ_s can be tuned from positive to negative values to cancel out ζ .

overall ZZ shift is given by $\zeta_{\text{tot}} = \zeta + \zeta_s$,

$$\zeta_s = J \frac{4\Omega_A\Omega_B}{\omega_A\omega_B}, \tag{C3}$$

where both contributions effectively arise as fourth-order perturbations. The sign of ζ_s depends upon the signs of J and Ω_μ , where, notably, J changes sign when moving across the off position in coupler flux [see Fig. 6(a)]. Thus with small adjustments in the qubit fluxes (so that the Ω_μ are nonzero) and the coupler flux, ζ_s can be used to cancel ζ . This leads to an overall vanishing ZZ shift $\zeta_{\text{tot}} = 0$.

We validate this understanding by calculating ζ_{tot} using the full Hamiltonian (A1)

$$\zeta_{\text{tot}}/2\pi = f_{11} - f_{01} - f_{10} + f_{00}, \tag{C4}$$

[see Fig. 6(b)]. The off position and $\zeta_{\text{tot}} = 0$ point are within $10^{-5}\Phi_0$ in the qubit fluxes according to the full model, relaxing the constraint of operating exactly on the sweet-spot contour. We need not worry about tuning of the qubit fluxes away from the sweet spot, as flux tuning at the $10^{-5}\Phi_0$ level is below the resolution of our dc bias source and contributes minimally to flux-noise induced dephasing.

APPENDIX D: EFFECTS DUE TO rf-FLUX CROSSTALK

In the presence of rf-flux crosstalk, where flux penetrates each of the qubit loops when we drive the coupler, dynamic effects arise that reduce the gate fidelity. For simplicity, we ignore the effects of the Gaussian envelope of the pulse in this appendix. The Hamiltonian of the system is

$$\begin{aligned}
 H_{\text{eff,ct}} &= - \sum_{\mu=A,B} \left(\frac{\omega_\mu}{2} \sigma_z^\mu + \Omega_{\text{ct},\mu} \cos(\omega_d t) \sigma_x^\mu \right) \\
 &\quad + J_{\text{ac}} \cos(\omega_d t) \sigma_x^A \sigma_x^B,
 \end{aligned} \tag{D1}$$

where $\Omega_{\text{ct},\mu}$ describes the maximum qubit-flux drive amplitude due to crosstalk. The drive frequency will typically be set to $f_d \approx f_{01} - f_{10}$ for an $\sqrt{i}$ SWAP-style gate or $f_d \approx f_{01} + f_{10}$ for a $\sqrt{b}$ SWAP-style gate, with $\omega_d = 2\pi f_d$. In each case, the drives are detuned from single-qubit transition frequencies. This unwanted drive thus dynamically shifts the qubit frequencies rather than inducing Rabi oscillations [46]. To see this, we first move to a frame rotating at the drive frequency. Making the RWA for the single-qubit drive terms while keeping all terms associated with the two-qubit drive, we obtain

$$H'_{\text{eff,ct}} = - \sum_{\mu=A,B} \left(\frac{\omega_\mu - \omega_d}{2} \sigma_z^\mu + \frac{\Omega_{\text{ct},\mu}}{2} \sigma_x^\mu \right) + J_{\text{ac}} \cos(\omega_d t) (\cos(\omega_d t) \sigma_x^A + \sin(\omega_d t) \sigma_y^A) \times (\cos(\omega_d t) \sigma_x^B + \sin(\omega_d t) \sigma_y^B). \quad (\text{D2})$$

As in Sec. C, we diagonalize the single-qubit terms in Eq. (D2) to second order in $\Omega_{\text{ct},\mu}/(\omega_\mu - \omega_d)$, yielding

$$H''_{\text{eff,ct}} = - \sum_{\mu=A,B} \frac{\omega_\mu + \delta\omega_\mu}{2} \sigma_z^\mu + J_{\text{ac}} \cos(\omega_d t) \left(\sigma_x^A + \frac{\Omega_{\text{ct},A}}{\omega_A - \omega_d} \sigma_z^A \right) \left(\sigma_x^B + \frac{\Omega_{\text{ct},B}}{\omega_B - \omega_d} \sigma_z^B \right), \quad (\text{D3})$$

where $\delta\omega_\mu = \Omega_{\text{ct},\mu}^2/2(\omega_\mu - \omega_d)$ and we have returned to the laboratory frame. Thus, the leading-order effects of ac-flux crosstalk are to renormalize the qubit frequencies as well as modify the effective two-qubit drive term from XX to a combination of XX , ZX , XZ , and ZZ . To avoid these unwanted dynamic effects, it is thus critical to cancel geometric flux crosstalk. We discuss the quantitative contribution of ac-flux crosstalk to gate infidelities in Appendix J.

APPENDIX E: EXPERIMENTAL SETUP

The experiment is performed in a Bluefors LD-250 dilution refrigerator with the wiring configured as shown in Fig. 7. The flux and charge inputs are attenuated at the 4-K stage and the mixing chamber with standard XMA attenuators, except the final 20-dB attenuator on the rf charge line (threaded copper). The dc- and rf-flux signals are combined in a bias tee (Mini-Circuits® ZFBT-4R2GW+), where the coupler bias tee is modified such that the capacitor is replaced with a short to further lower the high-pass cutoff frequency. The dc- and rf-flux lines included commercial low-pass filters (Mini-Circuits®) as indicated. The rf-flux and output lines also have additional low-pass filters with a sharp cutoff (8 GHz) from K&L microwave. Home-made Eccosorb (CR110) IR filters are added on the flux, input, and output lines, which further improves

the T_1 and T_2 coherences and reduces the qubit and resonator temperatures. The device is heat sunk to the base stage of the dilution refrigerator (stabilized at 15 mK) via an oxygen-free high-conductivity (OFHC) copper post, while surrounded by an inner lead shield thermalized via a welded copper ring. This is additionally surrounded by two cylindrical μ -metal cans (MuShield), thermally anchored using an inner close-fitting copper-shim sheet, attached to the copper can lid. We ensure that the sample shield is light tight, to reduce thermal photons from the environment.

APPENDIX F: DEVICE FABRICATION

The device (shown in Fig. 1 in the main text) is fabricated on a 430- μm -thick C-plane sapphire substrate. The base layer of the device, which includes the majority of the circuit (excluding the Josephson junctions), consists of 200 nm of tantalum with features fabricated via optical lithography and HF etch at wafer scale.

We perform standard cleaning using toluene, acetone, methanol, and isopropyl alcohol (TAMI) on the annealed sapphire substrates, followed with nanostrip etching at 50 °C for 10 min, and sulfuric acid etching at 140 °C for 10 min. We subsequently deposit 200 nm tantalum in an AJA ATC 2200 sputtering tool at 800 °C. A 2000-nm-thick layer of AZ 1518 is used as the (positive) photoresist and the large features are written using a Heidelberg MLA 150 Direct Writer. After 60 s of development with MIF 300 and a 10 min oven bake at 120 °C, we perform 20 s of HF etching using Ta etchant 1:1:1 (Transene Tantalum Etchant 111).

The junction mask is fabricated via electron-beam lithography with a bilayer resist (MMA-PMMA) comprised of MMA EL11 and 495 PMMA A6 spun at 4000 RPM. The e-beam lithography is performed on a 100 kV Raith EBPG5000 Plus E-Beam Writer. All Josephson junctions are made with the Dolan-bridge technique and etched for 2 min using a 3:1 DI:IPA solution at 6 °C. Aluminum was subsequently evaporated onto the chip in a Plassys electron-beam evaporator using double-angle evaporation ($\pm 21^\circ$), first depositing a 70-nm Al layer, performing static oxidation, and subsequently depositing a 90-nm Al layer. The wafer is then diced into 7×7 mm chips, mounted on a printed circuit board, and subsequently wire bonded.

APPENDIX G: READOUT AND ACTIVE RESET

We utilize the active-feedback capabilities of the Xilinx RFSoc field-programmable gate array (FPGA) board with the QICK open-source control code base. We perform simultaneous dispersive readout, using readout lengths of 10.4 and 18.2 μs , respectively. The readout data are then be processed on the FPGA board and compared to a previously calibrated threshold and the board conditionally plays a single-qubit π pulse to initialize the qubit to its ground state.

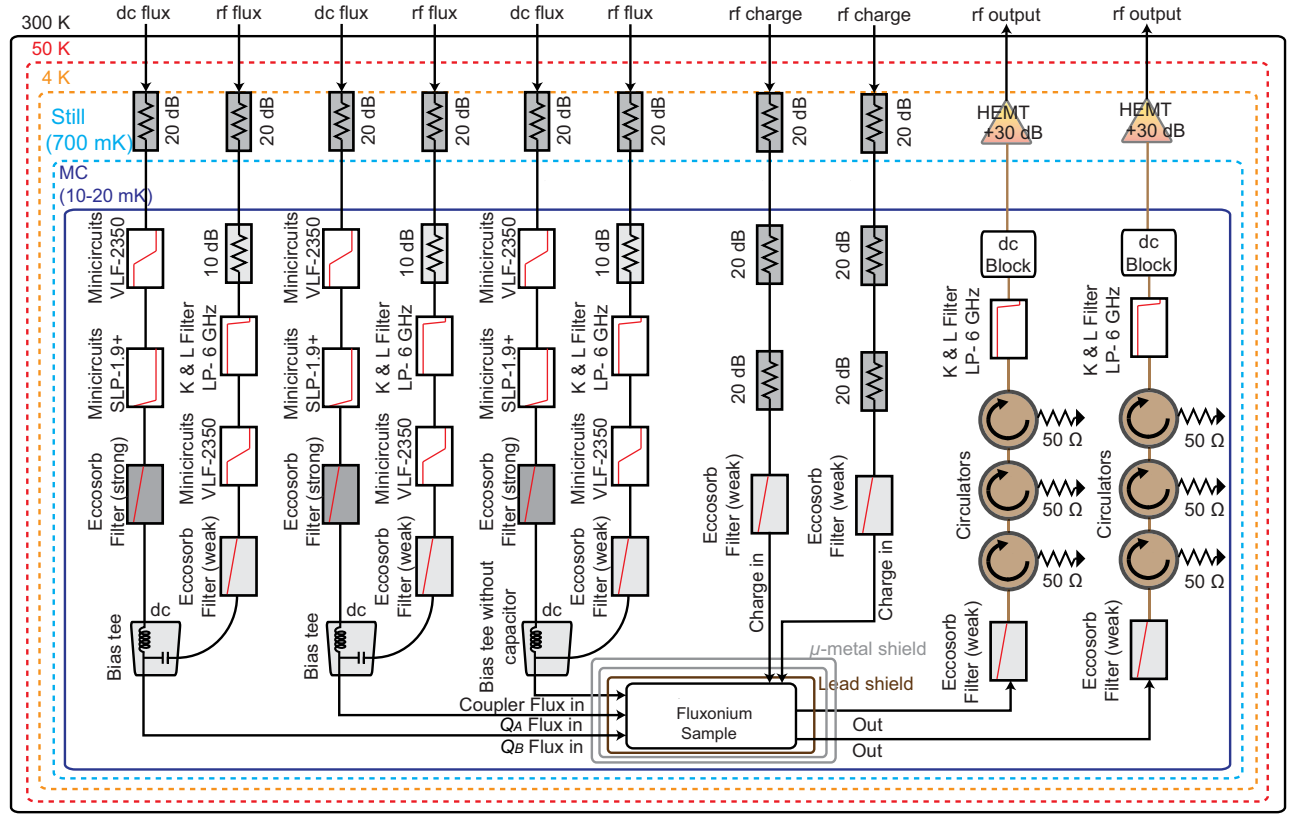


FIG. 7. The wiring diagram inside the dilution refrigerator. Outside the dilution fridge, there is 13–20 dB of attenuation and a dc block on the rf-flux line and an ultra-low-pass (<1 Hz) RC filter on the dc-flux line. Adding attenuation on the rf-flux lines at room temperature leads to a measured increase in the T_1 and T_2 coherences of the qubits. MC refers to mixing chamber.

We first take 10 000 readouts with the qubit uninitialized at the sweet spot. Because the Boltzmann temperature of the qubit (<2.8 mK) is lower than the temperature of the environment, we expect to see the qubit in thermal equilibrium. Indeed, we see approximately a 50:50 population split between the ground and excited states. Using a double-Gaussian function, we fit the data to determine the demarcation line that best classifies the qubit state for use in readout and active reset.

We measure our reset fidelity by initializing the qubit in $|g\rangle$ and $|e\rangle$ using active reset and then take another measurement right after the reset to obtain histogram shown in Fig. 8. We extract postselected active reset fidelities of 93% and 95%, respectively, for each qubit, this being very close to the readout fidelities due to the fast feedback time and high-fidelity single-qubit π pulse. By fitting the thermal population of the qubit ground and excited states, we can also measure the qubit temperatures to be approximately 50 mK.

APPENDIX H: FLUX-CROSSTALK CALIBRATIONS

The dc- and rf-flux crosstalk of the system are significant and require calibration to mitigate unwanted effects

that degrade gate fidelity. We measure the dc-flux crosstalk by performing 2D flux sweeps for different pairs of flux lines while probing the resonator. This reveals sharp

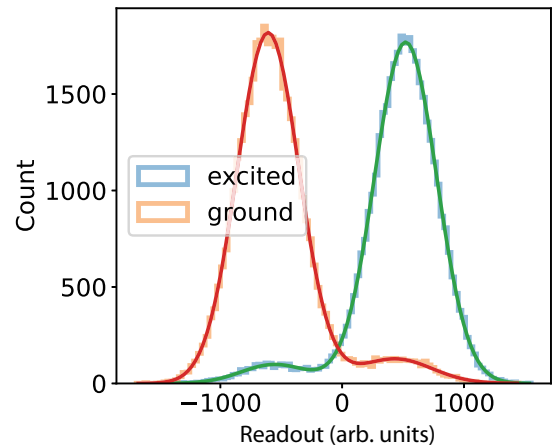


FIG. 8. A histogram of the readout data after initializing the qubit in either the ground or the excited state via active reset. The populations are then fitted to a double-Gaussian function and subsequently plotted as red and green solid lines. This fit is analyzed to determine the qubit temperature.

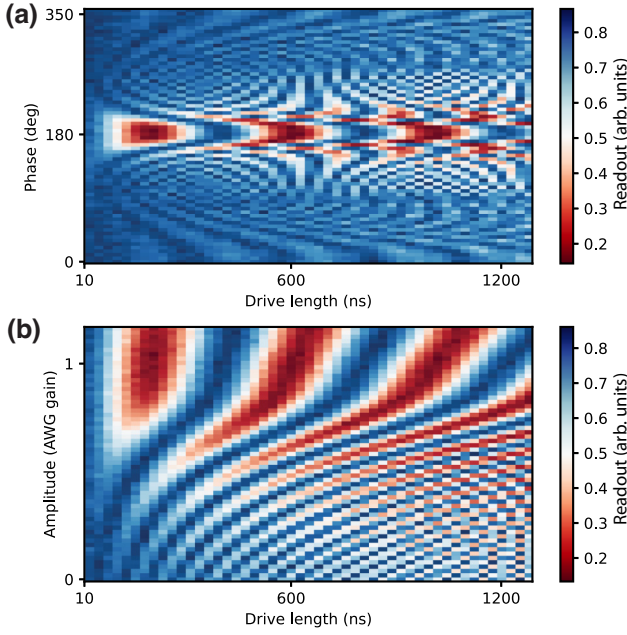


FIG. 9. (a) Performing a drive at the sum of qubit frequencies with various lengths while sweeping the phase of a cancellation pulse. The amplitude of this sweep is randomly chosen but it needs to be lower than the correct cancellation amplitude. (b) With the phase calibrated in (a), performing a drive at the sum of qubit frequencies with various lengths while sweeping the amplitude of a cancellation pulse.

flux-dependent features that originate from bringing qubit energy levels on resonance with the readout resonator. The slope of these lines is the dc-flux crosstalk of our system.

To minimize rf-flux crosstalk, we use compensation pulses that are played at the same time as the original drive pulse. These compensation pulses have the same length as the original pulse but we tune the phase and amplitude of these pulses to minimize the effect of flux crosstalk. Since the phases of these compensation pulses are independent parameters, we first calibrate them individually. Because the flux crosstalk can be understood as an off-resonant qubit drive, we would observe an ac Stark-shifted qubit frequency when performing a Rabi experiment. We Rabi drive at the $\sqrt{b\text{SWAP}}$ frequency, which is the sum of bare-qubit frequencies. The Rabi contrast is maximized when the qubit frequency shift is minimized, making this a good metric for measuring rf crosstalk. Therefore, we sweep the phase of the compensation pulse while playing it simultaneously with the drive pulse, as shown in Fig. 9(a). The maximum Rabi contrast of the $|00\rangle \leftrightarrow |11\rangle$ oscillation determines the correct compensation pulse phase.

After fixing the correct phases for both compensation channels, we determine the optimal cancellation pulse amplitudes in a similar sweep. As before, we look for the maximum Rabi contrast of the $|00\rangle \leftrightarrow |11\rangle$ oscillation but, in this case, we sweep the amplitude of the compensation

pulse, shown in Fig. 9(b). Because the cancellation gains from the two qubit channels will affect each other, we do this iteratively to find the optimal amplitudes for both of them.

Due to the linear nature of the flux crosstalk, the amplitudes of the drive and compensation pulses have a linear relationship and the phase difference between all three pulses is not amplitude dependent. With cancellation phases and amplitudes for one drive pulse calibrated, we can utilize this procedure to find compensation pulses for all $|00\rangle \leftrightarrow |11\rangle$ drive pulses. The two-qubit gates reported in this paper are all constructed in this way, with the coupler drive pulse and cancellation pulses on each qubit.

APPENDIX I: TWO-QUBIT-GATE CALIBRATIONS

We calibrate the $\sqrt{i\text{SWAP}}$ and $\sqrt{b\text{SWAP}}$ gates with gate sequences designed to amplify the gate errors. The gate calibration process consists of two steps, the rotation-angle calibration and phase calibrations. We can write the Hermitian matrix for a gate generated by a generic XX parametric drive on the coupler as

$$\sqrt{\phi_b\text{SWAP}} = \begin{pmatrix} \cos \theta & 0 & 0 & ie^{i\phi_D} \sin \theta \\ 0 & e^{i\phi_{01}} & 0 & 0 \\ 0 & 0 & e^{i\phi_{10}} & 0 \\ ie^{i(\phi_{11}-\phi_D)} \sin \theta & 0 & 0 & e^{i\phi_{11}} \cos \theta \end{pmatrix} \quad (11)$$

for $|00\rangle \leftrightarrow |11\rangle$ oscillation and

$$\sqrt{\phi_i\text{SWAP}} = \begin{pmatrix} 1 & 0 & 0 & 0 \\ 0 & e^{i\phi_{01}} \cos \theta & ie^{i(\phi_{01}+\phi_D)} \sin \theta & 0 \\ 0 & ie^{i(\phi_{10}-\phi_D)} \sin \theta & e^{i\phi_{10}} \cos \theta & 0 \\ 0 & 0 & 0 & e^{i\phi_{11}} \end{pmatrix} \quad (12)$$

for $|01\rangle \leftrightarrow |10\rangle$ oscillation, where ϕ_D is the phase of the coupler drive, ϕ_{01} , ϕ_{10} , and ϕ_{11} are phases due to the frequency shift of levels while the drive is on, which have the relationship $\phi_{11} = \phi_{01} + \phi_{10} + \phi_{zz}$ [47]. In our system, since all frequency shifts and the ZZ term during the parametric drive are small, we have $\phi_{11} \approx \phi_{01} + \phi_{10}$ and all of ϕ_{01} , ϕ_{10} , and ϕ_{11} are close to 0. We first calibrate the rotation angle (θ). We fix the pulse length for $\sqrt{i\text{SWAP}}$ at $99\,000/384 \approx 257.8$ ns and for $\sqrt{b\text{SWAP}}$ at $39\,000/384 \approx 101.6$ ns. Since our arbitrary wave-form generator (AWG) (Xilinx RFSoc) has a 384-MHz processor, the pulse lengths are integer multiples of $1000/384$ ns. We initialize the system in state $|00\rangle$, sweep the pulse amplitude while playing the same pulse consecutively $4n + 2$ times, and look for the amplitude that gives us the highest-fidelity $|11\rangle$ state. By playing the same gate for up to 402 times, we can obtain the value of parameter θ up to 1×10^{-4} in precision.

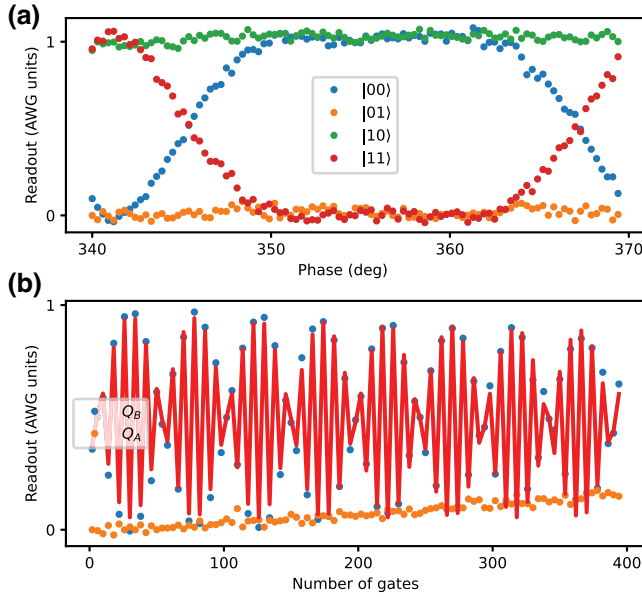


FIG. 10. (a) Playing the pulse sequence in Fig. 12 while sweeping the phase of qubit- A phase gates (Z_A). At $\phi_A = 357^\circ$, the phase of $\phi_{01} + \phi_{10}$ is perfectly cancelled; thus $\phi_{01} + \phi_{10} = 3$. (b) Playing the pulse sequence in Fig. 13 with various copies of the $\sqrt{b}$ SWAP gates and measuring the final state of both qubits. With this sequence, qubit A should only see a decay process to thermal equilibrium and the qubit- B state dependence on the number of gates is shown in Eqs. 13. By fitting the data, we can extract the value of ϕ_{01} and ϕ_{10} .

With θ calibrated to be $\pi/4$, gate phases ϕ_{01} , ϕ_{10} , ϕ_{11} , and ϕ_D are subsequently calibrated. Since the calibration process is very similar for $\sqrt{i}$ SWAP and $\sqrt{b}$ SWAP gates, here we only use $\sqrt{b}$ SWAP as an example for explanation. We calibrate these phases with the sequence shown in Fig. 12, where Z_A and Z_B are single-qubit phase gates on each qubit with phase ϕ_A and ϕ_B . A unit consists of one $\sqrt{b}$ SWAP gate and two single-qubit Z gates, and we note that with $4n + 2$ units, it is only when $\phi_A + \phi_B = -\phi_{11}$ that we obtain a b SWAP gate up to some phases. Thus we play a sequence of 321 units while sweeping ϕ_A (shown in Fig. 10) and measure ϕ_{11} to be around -3 degrees. We subsequently play the sequence as shown in Fig. 13 and with $4n + 2$ units, we have the qubit- B ground-state population,

$$\frac{1}{2}(1 + (-1)^n \sin(4n(\phi_{10} - \phi_{11}) + 2(\phi_{10} - \phi_{11}) + \phi_D)). \quad (13)$$

The qubit- A ground-state population should always be 0 for all the n values. Fitting this function gives us $\phi_{10} - \phi_{11}$ and $2\phi_{10} - 2\phi_{11} + \phi_D$ (shown in Fig. 10). With the ϕ_{11} value measured from the above step, we can derive ϕ_{10} , ϕ_{11} , and ϕ_D . Since ϕ_{ZZ} is very small in our system, we can calculate ϕ_{01} as $\phi_{11} - \phi_{10}$ and the result is very close to

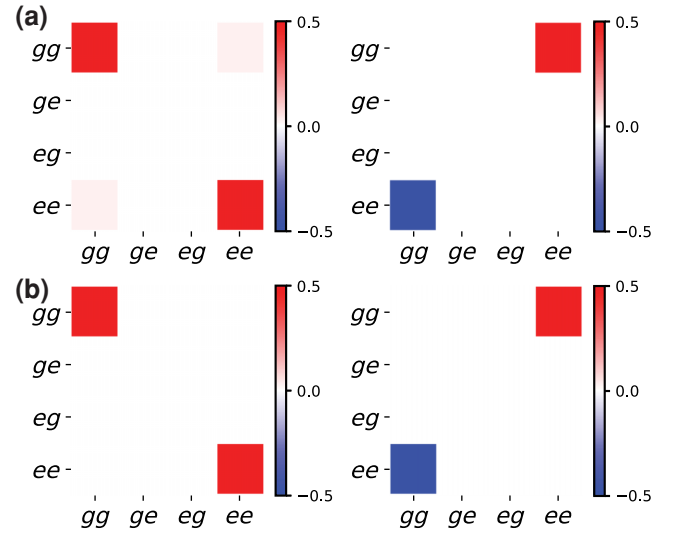


FIG. 11. Direct preparation of the $|gg\rangle + i|ee\rangle$ Bell state using a $\sqrt{i}$ SWAP gate on the initialized $|gg\rangle$ state. (a) State tomography provides experimental data of the density matrix of this state. On the left is the real part and on the right is on the imaginary part. The purity and state fidelity are 95%, limited by SPAM errors. (b) The density matrix of the ideal $|gg\rangle + i|ee\rangle$, calculated using the theory, for comparison.

directly measuring ϕ_{01} by switching operations on qubits A and B .

Using the calibrated values, we adjust the phases of the virtual Z gates following the parametric coupler drive, such that the qubit- A Z gate has phase $\phi_A = -\phi_{10}$, the qubit- B Z gate has phase $\phi_B = -\phi_{01}$, and the coupler drive has phase $-\phi_D$. In this experiment, all the single-qubit Z gates are virtual; therefore we only need to update the phase of the pulses after a $\sqrt{b}$ SWAP or $\sqrt{i}$ SWAP gate for each qubit. One characterization of our calibrated gate is done by executing quantum state tomography (QST). We prepare the Bell state $|gg\rangle + i|ee\rangle$ using the application of a $\sqrt{i}$ SWAP gate, as shown in Fig. 11. This measurement shows a state purity and state fidelity of 95%, limited by state preparation and measurement (SPAM) errors. Then, we execute quantum process tomography, performing QST measurements on the complete two-qubit basis states to extract the full process matrix, as shown in Fig. 14.

APPENDIX J: ERROR BUDGETING

Various sources contribute to the single- and two-qubit gate infidelities, including qubit decay, heating, dephasing, carrier-envelope variations, beyond-RWA effects, and rf-flux crosstalk. In this appendix, we quantify the contribution of each error source to the infidelity via QuTiP simulations and analytical estimates (where possible).

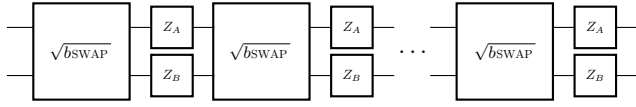


FIG. 12. The gate sequence for calibrating the $\sqrt{b}\text{SWAP}$ gate phase ϕ_{11} .

Simulations suggest that leakage to noncomputational states is negligible and attributable to the significant detuning between relevant drive frequencies and undesired transition frequencies. We can thus safely truncate the Hilbert space to the computational subspace. In the following, we focus on the specific example of error budgeting two-qubit gates, with similar results holding for single-qubit gates. In the presence of a coupler-flux drive, the laboratory-frame Hamiltonian is

$$H = -\frac{\omega_A}{2}\sigma_z^A - \frac{\omega_B}{2}\sigma_z^B + Af(t)\cos(\omega_d t + \theta_{\text{CE}})\sigma_x^A\sigma_x^B, \quad (\text{J1})$$

where A is the amplitude of the drive, $f(t)$ is the Gaussian envelope, and θ_{CE} is the carrier-envelope phase.

1. Beyond the RWA

Both qubits in our sample have Larmor periods of about 20 ns, only a slightly smaller time scale than the single- and two-qubit gates that we implement. Thus, it is possible that fidelities could begin to be limited by effects arising from counter-rotating terms. To obtain a semianalytical estimate of the associated fidelity reduction, we utilize a Magnus expansion [49–51] following Ref. [27]. Noting that the Hamiltonian only couples pairs of states $|00\rangle \leftrightarrow |11\rangle$ and $|01\rangle \leftrightarrow |10\rangle$, we write the Hamiltonian (J3) as a direct sum $H_{2q}(t) = H_-(t) \oplus H_+(t)$, where

$$H_{\pm}(t) = -\frac{\omega_{\pm}}{2}\Sigma_z^{\pm} + Af(t)\cos(\omega_d t)\Sigma_x^{\pm}. \quad (\text{J2})$$

We define $\omega_{\pm} = \omega_a \pm \omega_b$ and the Pauli matrices as, e.g., $\Sigma_x^+ = |00\rangle\langle 11| + \text{H.c.}$ and $\Sigma_x^- = |01\rangle\langle 10| + \text{H.c.}$ For simplicity, we set $\theta_{\text{CE}} = 0$ and postpone a discussion of carrier-envelope variations to Sec. J2. To isolate the effects of the drive, we move into a rotating frame, yielding

$$H'_{\pm}(t) = Af(t)\cos(\omega_d t)[\cos(\omega_{\pm} t)\Sigma_x^{\pm} + \sin(\omega_{\pm} t)\Sigma_y^{\pm}]. \quad (\text{J3})$$

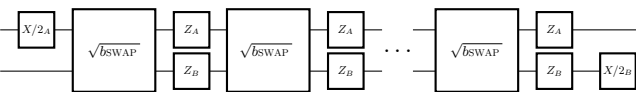


FIG. 13. The gate sequence for calibrating the $\sqrt{b}\text{SWAP}$ gate phases ϕ_{10} and ϕ_D .

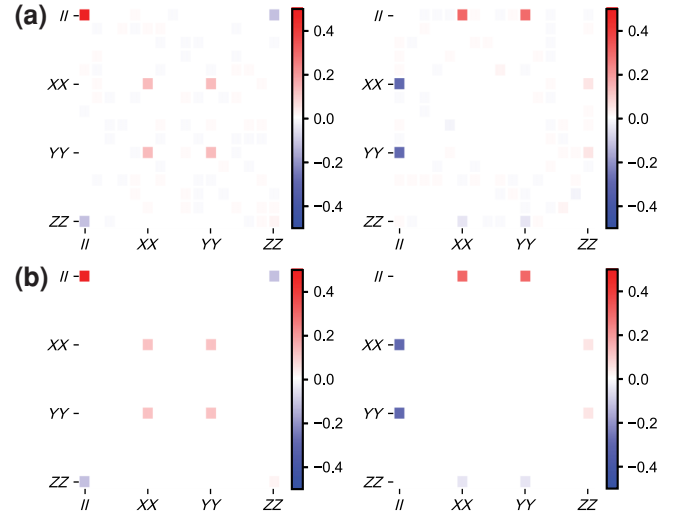


FIG. 14. (a) The experimental data of the process tomography on the $\sqrt{i}\text{SWAP}$ gate, where the left side shows the real part and the right side shows the imaginary part. (b) The process tomography of an ideal $\sqrt{i}\text{SWAP}$ gate, calculated using the theory.

Utilizing the first two terms in the Magnus expansion, the propagator is $U_{2q}(t) = \exp(\Delta_1^-[t] + \Delta_1^+[t] + \Delta_2^-[t] + \Delta_2^+[t])$, where [49–51]

$$\Delta_{1,\pm}(t) = -i \int_0^t H'_{\pm}(t') dt', \quad (\text{J4})$$

$$\Delta_{2,\pm}(t) = -\frac{1}{2} \int_0^t dt_1 \int_0^{t_1} dt_2 [H'_{\pm}(t_1), H'_{\pm}(t_2)]. \quad (\text{J5})$$

The gate time τ is taken to be $\tau = \sqrt{2\pi}/(A \text{erf}(\sqrt{2}))$, appropriate to obtain a $\sqrt{i}\text{SWAP}$ or $\sqrt{b}\text{SWAP}$ in the RWA with Gaussian envelope $f(t) = \exp(-0.5t^2/(\sigma^2))$ and width $\sigma = \tau/4$.

For the first terms in the Magnus expansion, we obtain

$$\begin{aligned} \Delta_{1,-}(\tau) + \Delta_{1,+}(\tau) &= -i\alpha_- \Sigma_x^- - i\alpha_+ \Sigma_x^+ \\ &= -i\frac{\alpha_-}{2}(\sigma_x^a \sigma_x^b + \sigma_y^a \sigma_y^b) \\ &\quad - i\frac{\alpha_+}{2}(\sigma_x^a \sigma_x^b - \sigma_y^a \sigma_y^b), \end{aligned} \quad (\text{J6})$$

where

$$\alpha_{\pm} = \int_0^{\tau} dt Af(t)\cos(\omega_d t)\cos(\omega_{\pm} t). \quad (\text{J7})$$

These terms describe the desired drive ($\alpha_- = \pi/4, \alpha_+ = 0$ for $\sqrt{i}\text{SWAP}$ and $\alpha_+ = \pi/4, \alpha_- = 0$ for $\sqrt{b}\text{SWAP}$) as well as an undesired term that causes transitions between, e.g.,

$|00\rangle \leftrightarrow |11\rangle$ in the case of $\sqrt{i\text{SWAP}}$. For the second-order terms, we obtain

$$\begin{aligned}\Delta_{2,-}(\tau) + \Delta_{2,+}(\tau) &= -i\beta_- \Sigma_z^- - i\beta_+ \Sigma_z^+ \\ &= -i\frac{\beta_+ + \beta_-}{2}\sigma_z^a - i\frac{\beta_+ - \beta_-}{2}\sigma_z^b, \quad (\text{J8})\end{aligned}$$

where

$$\begin{aligned}\beta_{\pm} &= A^2 \int_0^{\tau} dt_1 \int_0^{t_1} dt_2 f(t_1) f(t_2) \cos(\omega_d t_1) \cos(\omega_d t_2) \\ &\quad \times [\cos(\omega_{\pm} t_1) \sin(\omega_{\pm} t_2) - \sin(\omega_{\pm} t_1) \cos(\omega_{\pm} t_2)]. \quad (\text{J9})\end{aligned}$$

These terms describe the familiar Bloch-Siegert shift, where the resonance frequencies of both qubits are shifted by the coupler drive.

As an aside, we comment that we have just derived the propagator to second order for single-qubit gates with a drive on σ_x (returning to the usual Pauli-matrix notation for clarity), $U_{1q}(t) = \exp(-i\frac{1}{2}\alpha\sigma_x - i\frac{1}{2}\beta\sigma_z)$, dropping the subscripts on α and β , and redefining α and β with an additional factor of 2 for later convenience.

Returning to two-qubit gates, we now specialize to the case of $\sqrt{i\text{SWAP}}$ with $\omega_d = \omega_a - \omega_b$. A similar analysis follows for $\sqrt{b\text{SWAP}}$ with $\omega_d = \omega_a + \omega_b$. The propagator in this case is

$$\begin{aligned}U_{2q}(\tau) &= \exp\left(-i\frac{1}{2}\left[\frac{\pi}{4} + \delta\right][\sigma_x^a \sigma_x^b + \sigma_y^a \sigma_y^b] \right. \\ &\quad \left. - i\frac{\alpha_+}{2}[\sigma_x^a \sigma_x^b - \sigma_y^a \sigma_y^b] \right. \\ &\quad \left. - i\frac{\beta_+ + \beta_-}{2}\sigma_z^a - i\frac{\beta_+ - \beta_-}{2}\sigma_z^b\right), \quad (\text{J10})\end{aligned}$$

where we have isolated the deviation of α_- from the ideal value of $\pi/4$, $\alpha_- = (\pi/4) + \delta$. We may now read off the Bloch-Siegert shifts $\omega_{\text{BS},\mu}$, given by $\omega_{\text{BS},a} = (\beta_+ + \beta_-)/\tau$ and $\omega_{\text{BS},b} = (\beta_+ - \beta_-)/\tau$. With the propagator in hand, we may now compute the gate fidelity using the standard formula [52]

$$F = \frac{\text{Tr}[U^\dagger(\tau)U(\tau)] + \left|\text{Tr}[U_T^\dagger U(\tau)]\right|^2}{d(d+1)}, \quad (\text{J11})$$

where d is the dimension of the Hilbert space and U_T is the target unitary. Expanding $\text{Tr}[U_T^\dagger U(\tau)]$ about $(\delta, \alpha_+, \beta_-, \beta_+) = (0, 0, 0, 0)$ and retaining only leading-order terms, we obtain

$$F = 1 - \frac{2}{5}\left(\alpha_+^2 + \delta^2 + \beta_+^2 + \frac{8}{\pi^2}\beta_-^2\right), \quad (\text{J12})$$

in the case of $\sqrt{i\text{SWAP}}$ and

$$F = 1 - \frac{2}{5}\left(\alpha_-^2 + \delta^2 + \beta_-^2 + \frac{8}{\pi^2}\beta_+^2\right), \quad (\text{J13})$$

in the case of $\sqrt{b\text{SWAP}}$ (with δ now defined as $\alpha_+ = (\pi/4) + \delta$). Evaluating the integrals $\alpha_{\pm}, \beta_{\pm}$ numerically, we obtain $1 - F = 1.4 \times 10^{-4}$ and 1.1×10^{-5} , in the cases of $\sqrt{i\text{SWAP}}$ and $\sqrt{b\text{SWAP}}$, respectively. For the Bloch-Siegert shifts, we obtain $|\omega_{\text{BS},a}|/2\pi = 9$ kHz and $|\omega_{\text{BS},b}|/2\pi = 20$ kHz in the case of $\sqrt{i\text{SWAP}}$ and $|\omega_{\text{BS},a}|/2\pi = 11$ kHz and $|\omega_{\text{BS},b}|/2\pi = 2$ kHz in the case of $\sqrt{b\text{SWAP}}$.

We compare the fidelity results with estimates obtained by numerical simulation of Eq. (J3) using QuTiP [53]. These simulations yield infidelity contributions of 8.4×10^{-5} and 1.3×10^{-5} for $\sqrt{i\text{SWAP}}$ and $\sqrt{b\text{SWAP}}$, respectively. In both cases, the analytically estimated values are within about a factor of 2 of the numerically obtained infidelities.

In the case of single-qubit gates with $U_T = \sqrt{X}_\mu$, we obtain, for the fidelity to leading order,

$$F = 1 - \frac{4\beta^2}{3\pi^2} - \frac{\delta^2}{6}, \quad (\text{J14})$$

where $\delta = \alpha - (\pi/2)$. We obtain infidelity estimates of 7.8×10^{-5} and 7.5×10^{-5} for $\sqrt{X}_a$ and $\sqrt{X}_b$, respectively. Performing numerical simulations [with the single-qubit version of Eq. (J3)], we obtain infidelities of 5.6×10^{-5} in both cases. These results are slightly lower than the analytical estimates but of the same order of magnitude.

2. Carrier-envelope variations

The phase θ_{CE} is constantly updated during the experiment. As the logical states are defined in the rotating frame, the phase of the pulse should be matched with the dynamical phase difference of the states being swapped. Besides, we make use of the phase θ_{CE} to realize virtual Z gates. Because the pulse length is only four (11) drive periods in the case of the $\sqrt{i\text{SWAP}}$ ($\sqrt{b\text{SWAP}}$) gate, the energy carried by the pulse is generally a function of θ_{CE} (to be contrasted with the more standard case in which the pulse length is much larger than the drive period and there is no such dependence on θ_{CE}). Additionally, the effects of the counter-rotating terms can depend on θ_{CE} . To quantify the contribution of this source of error, we numerically sweep the phase of the pulse and calculate the gate infidelity as a function of θ_{CE} . The average of the increase in infidelity due to phase variation is what is taken as the contribution from carrier-envelope phase in Table II.

TABLE II. The error budget for single- and two-qubit gates. Analytical estimates of decoherence rates can be found in Ref. [48]. We use gate lengths $\tau = 83.3, 65.1, 101.6$, and 257.8 ns for the gates $\sqrt{X_a}$, $\sqrt{X_b}$, $\sqrt{b\text{SWAP}}$, and $\sqrt{i\text{SWAP}}$, respectively. The unaccounted error is attributed to insufficient calibration and rf-flux crosstalk.

Error source	$\sqrt{i\text{SWAP}}$ Estimated (Simulated)	$\sqrt{b\text{SWAP}}$ Estimated (Simulated)	$\sqrt{X_a}$ Estimated (Simulated)	$\sqrt{X_b}$ Estimated (Simulated)
Decay	4.6×10^{-4} (4.6×10^{-4})	1.8×10^{-4} (1.8×10^{-4})	1.5×10^{-4} (1.5×10^{-4})	1.1×10^{-4} (1.2×10^{-4})
Heating	4.6×10^{-4} (4.6×10^{-4})	1.8×10^{-4} (1.8×10^{-4})	1.5×10^{-4} (1.5×10^{-4})	1.1×10^{-4} (1.2×10^{-4})
Dephasing	3.0×10^{-4} (3.0×10^{-4})	1.2×10^{-4} (1.2×10^{-4})	1.0×10^{-4} (1.0×10^{-4})	7.5×10^{-5} (7.5×10^{-5})
Beyond RWA	1.4×10^{-4} (8.4×10^{-5})	1.1×10^{-5} (1.3×10^{-5})	5.2×10^{-5} (5.6×10^{-5})	7.5×10^{-5} (5.6×10^{-5})
Carrier-envelope phase	(5.8×10^{-5})	(1.4×10^{-5})	(0.5×10^{-5})	(0.5×10^{-5})
Higher-order drive terms	(8.5×10^{-5})	(2.3×10^{-5})	(1.4×10^{-5})	(2.2×10^{-5})
Estimated infidelity (decoherence)	1.2×10^{-3}	4.8×10^{-4}	4.0×10^{-4}	3.0×10^{-4}
Simulated infidelity (all)	1.4×10^{-3}	5.3×10^{-4}	4.7×10^{-4}	3.7×10^{-4}
Measured infidelity	2.8×10^{-3}	9×10^{-4}	6×10^{-4}	5×10^{-4}

3. Higher-order drive terms

As discussed in Ref. [27], the form of the drive operator in Eq. (J1) is an approximation. In reality, the drive operator associated with $\Phi_{\text{ext},C}$ is not perfectly XX but includes also nonzero IX , XI , and other components. Similarly, for the drive operators associated with $\Phi_{\text{ext},A}$ and $\Phi_{\text{ext},B}$, the drive operators contain nonzero ZX , XZ , and other terms. Including these additional drive terms in the simulations contributes infidelities on the order of 10^{-5} (see Table II).

4. Decoherence

The gate fidelity is reduced due to decay, heating, and dephasing effects. In the following, we specialize to the case of the $\sqrt{i\text{SWAP}}$ gate, taking $\omega_d = |\omega_b - \omega_a|$. The discussion follows similarly for the case of $\sqrt{b\text{SWAP}}$, with $\omega_d = \omega_b + \omega_a$. The Hamiltonian after performing the RWA is

$$H'_{\text{RWA}} = \frac{A}{4}(\sigma_x^A \sigma_x^B + \sigma_y^A \sigma_y^B). \quad (\text{J15})$$

We perform numerical simulations of the Lindblad master equation

$$\frac{d\rho(t)}{dt} = -i[H'_{\text{RWA}}, \rho(t)] + \sum_k \Gamma_k \mathcal{D}(L_k) \rho(t), \quad (\text{J16})$$

where

$$\mathcal{D}(L)\rho = L\rho L^\dagger - \frac{1}{2}\{L^\dagger L, \rho\}$$

is the dissipator and $\rho(t)$ is the system density matrix. We include collapse operators σ_-^μ , σ_+^μ , and σ_z^μ and associated decay rates $\Gamma_1/2$, $\Gamma_1/2$, and $\Gamma_\phi/2$, respectively ($\mu = \{A, B\}$). The factors of $1/2$ in the decay and heating rates are due to the equal contributions of decay and heating to T_1 , while the factor of $1/2$ in the dephasing rate ensures that coherences decay at the appropriate rate [48]. By turning on each decoherence channel one at a time, we numerically estimate the contribution of each (see Table II). We then proceed to turn on all decoherence channels to estimate the overall fidelity reduction due to decoherence. For both the $\sqrt{b\text{SWAP}}$ and $\sqrt{i\text{SWAP}}$ gates, decoherence makes up about half of the measured infidelity.

Analytical estimates of the first-order contribution of decoherence to the infidelity are given in Ref. [48] and we reproduce them here for completeness:

$$F \approx 1 - \frac{d}{2(d+1)} \tau \sum_\mu (\Gamma_1^\mu + \Gamma_\phi^\mu), \quad (\text{J17})$$

where τ is the duration of the gate and d is the dimension of the Hilbert space. Infidelity estimates using this formula for single- and two-qubit gates can be found in Table II. We find excellent agreement between the numerical results and analytical formulas.

5. The rf-flux crosstalk

As discussed in Appendix D, flux crosstalk can contribute to dynamic frequency shifts and unwanted entanglement. Defining the maximum fluxes due to crosstalk ξ_μ through the qubit loops, the qubit drive amplitudes are $\Omega_{\text{ct},\mu} = \xi_\mu E_{L\mu} \langle 0|\phi_\mu|1\rangle$, where $\mu = a, b$. To estimate the infidelity associated with such crosstalk, we substitute Eq. (D1) for Eq. (J1), including the Gaussian envelope and transforming into the rotating frame with the qubit frequencies. For $\xi_\mu/2\pi = 10^{-4}$, we find numerically that the infidelity is 1.2×10^{-6} and 1.2×10^{-5} for $\sqrt{b\text{SWAP}}$ and $\sqrt{i\text{SWAP}}$, respectively, below the levels to which we are sensitive. However, if crosstalk rises to the level of $\xi_\mu/2\pi = 10^{-3}$, the infidelities rise to 1.1×10^{-3} and 0.069 for $\sqrt{b\text{SWAP}}$ and $\sqrt{i\text{SWAP}}$, respectively. These infidelities would be the leading source of error, necessitating the careful flux-crosstalk cancellation that we undertake in our experiment.

6. Overall error budget

With all of the error channels included, the infidelities of the single-qubit, $\sqrt{i\text{SWAP}}$, and $\sqrt{b\text{SWAP}}$ gates are reduced to 99.97%, 99.87%, and 99.95%, respectively. Our numerical simulations suggest that the gate fidelity is predominantly constrained by decoherence. The remaining error is attributed to insufficient calibration and rf-flux crosstalk.

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